Electronic Patent Application Fee Transmittal						
Application Number:	10	10812015				
Filing Date:	30-Mar-2004					
Title of Invention:	Gallium nitride (GaN)-based semiconductor light emitting diode and method for manufacturing the same					
First Named Inventor/Applicant Name:	Seung Wan Chae					
Filer:	Benjamin J. Hauptman/Ayesha Wilson					
Attorney Docket Number:	2336-255					
Filed as Large Entity						
Utility Filing Fees						
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)	
Basic Filing:						
Pages:						
Claims:						
Miscellaneous-Filing:						
Petition:						
Patent-Appeals-and-Interference:						
Post-Allowance-and-Post-Issuance:						
Extension-of-Time:						
Extension - 2 months with \$120 paid		1252	1	330	330	

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)				
Miscellaneous:								
Request for continued examination	1801	1	790	790				
	Tota	1120						